

Si photodiode

S8559

Detector for X-ray monitor

Features

- Applications
- ➡ Si photodiode coupled to low cost CsI scintillator
- X-ray detection
- Ideal for detection of X-ray energy below 100 keV
- X-ray monitors

■ Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Reverse voltage	VR Max.	5	V
Operating temperature	Topr	-10 to +60	°C
Storage temperature	Tstg	-20 to +70	°C

■ Electrical and optical characteristics (without scintillator, Ta=25 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	190 to 1000	-	nm
Peak sensitivity wavelength	λр			720	-	nm
Photo sensitivity	S	λ=500 nm	-	0.26	-	A/W
Dark current	ID	VR=10 mV	-	2	50	pА
Terminal capacitance	Ct	VR=0 V, f=10 kHz	-	950	-	pF

I→ X-ray sensitivity (reference value, tube current: 1.0 mA, aluminum filter: t=6 mm, distance=830 mm)

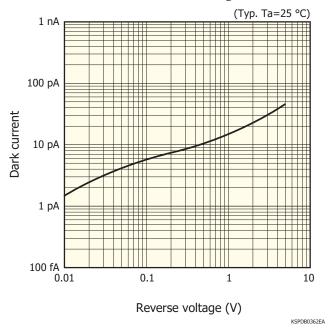
X-ray tube voltage	Тур.	Unit
120 kV	52	nA

Note) Depends on equipment and measurement conditions.

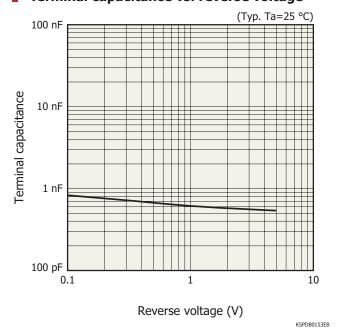
Handling precautions

Avoid storing or using S8559 at high humidity because CsI scintillator has deliquescence.

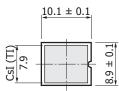
Dark current vs. reverse voltage

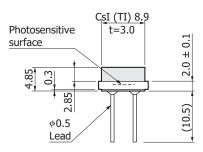


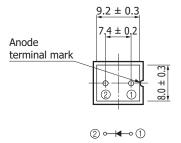
► Terminal capacitance vs. reverse voltage



Dimensional outline (unit: mm)







VSDDA0145ER

Si photodiode

S8559

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- · Metal, ceramic, plastic package products
- Technical information
- · Si photodiode/Application circuit examples

Information described in this material is current as of August 2020.

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